

Features

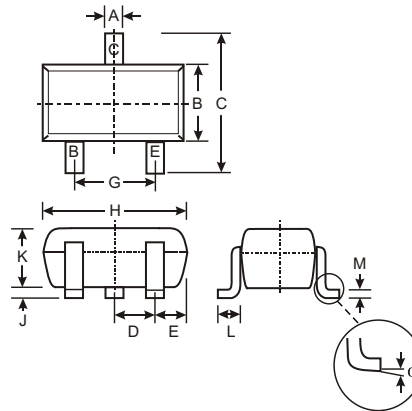
Ideally Suited for Automatic Insertion
 Epitaxial Planar Die Construction
 For Switching, AF Driver and Amplifier Applications
 Complementary PNP Types Available (BC807-xxW)
Lead Free By Design/RoHS Compliant (Note 1)
"Green" Device (Note 2)

Mechanical Data

Case: SOT-323
 Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
 Moisture Sensitivity: Level 1 per J-STD-020C
 Terminals: Finish – Matte Tin annealed over Alloy 42
 leadframe. Solderable per MIL-STD-202, Method 208
 Pin Connections: See Diagram

Marking:

P/N	Marking
BC817-16W	K6A
BC817-25W	K6B
BC817-40W	K6C



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
	0	8
All Dimensions in mm		

Ordering & Date Code Information: See Page 3

Approximate Weight: 0.006 grams

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EB0}	5.0	V
Collector Current	I _C	500	mA
Peak Collector Current	I _{CM}	1000	mA
Peak Emitter Current	I _{EM}	1000	mA
Power Dissipation at T _{SB} = 50°C (Note 3)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R _{JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic (Note 4)	Symbol	Min	Max	Unit	Test Condition
DC Current Gain	h _{FE}	100	250	—	V _{CE} = 1.0V, I _C = 100mA
Current Gain Group -16		160	400		V _{CE} = 1.0V, I _C = 300mA
-25		250	600		
-40		60	—		
Current Gain Group -16	h _{FE}	60	—	—	V _{CE} = 1.0V, I _C = 300mA
-25		100	—		
-40		170	—		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.7	V	I _C = 500mA, I _B = 50mA
Base-Emitter Voltage	V _{BE}	—	1.2	V	V _{CE} = 1.0V, I _C = 300mA
Collector-Emitter Cutoff Current	I _{CES}	—	100 5.0	nA μA	V _{CE} = 45V V _{CE} = 25V, T _J = 150°C
Emitter-Base Cutoff Current	I _{EB0}	—	100	nA	V _{EB} = 4.0V
Gain Bandwidth Product	f _T	100	—	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 50MHz
Collector-Base Capacitance	C _{CBO}	—	12	pF	V _{CB} = 10V, f = 1.0MHz

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Short duration pulse test used to minimize self-heating effect.

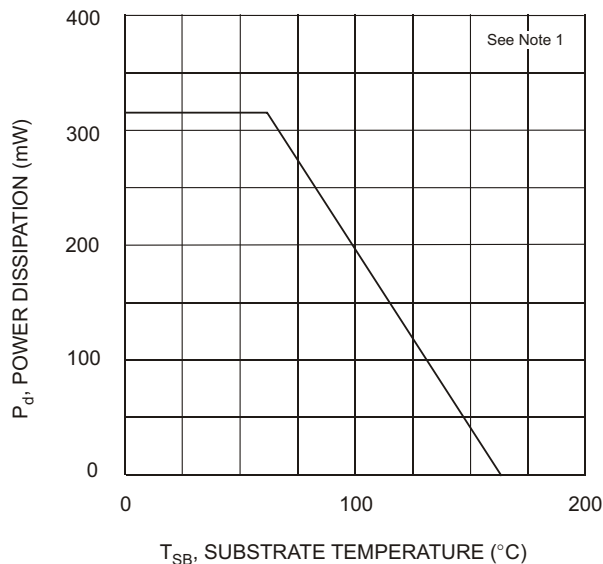


Fig. 1, Power Derating Curve

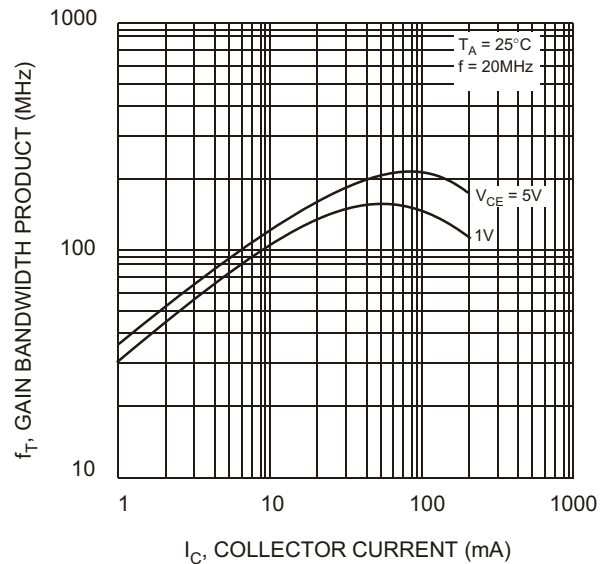


Fig. 2, Gain-Bandwidth Product vs Collector Current

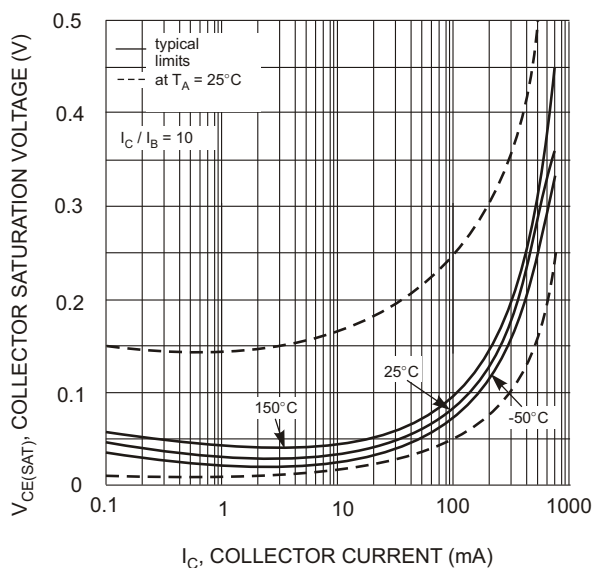


Fig. 3, Collector Sat. Voltage vs Collector Current

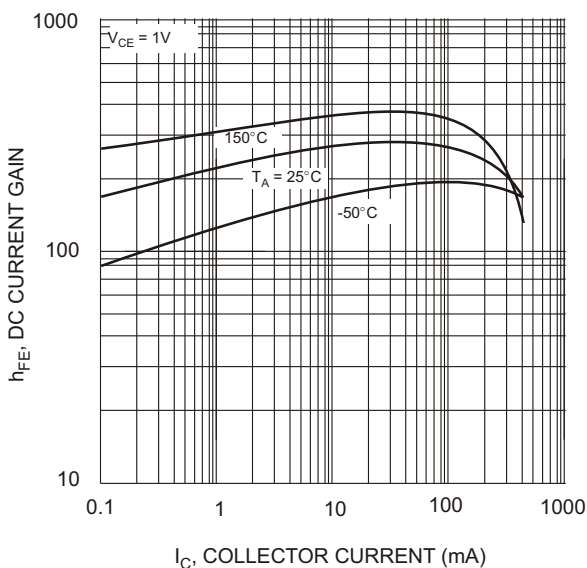


Fig. 4, DC Current Gain vs Collector Current

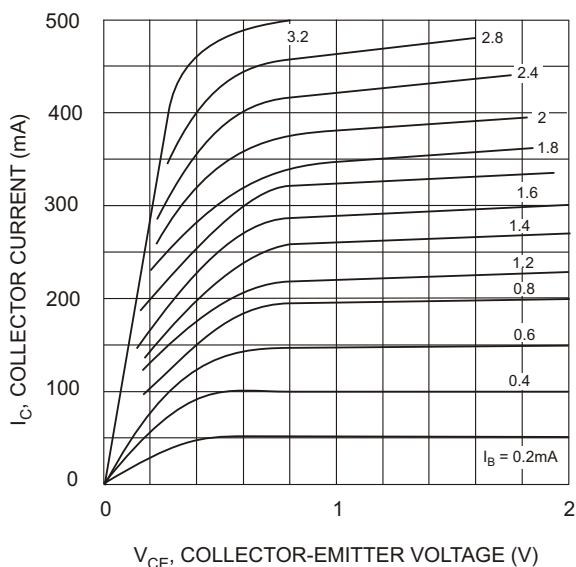


Fig. 5, Typical Emitter-Collector Characteristics

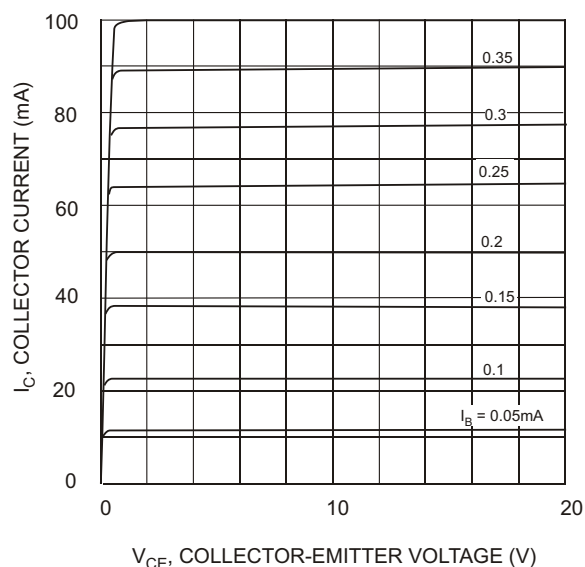


Fig. 6, Typical Emitter-Collector Characteristics

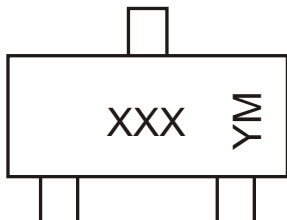
Ordering Information (Note 5)

Device*	Packaging	Shipping
BC817-xxW-7	SOT-323	3000/Tape & Reel

Notes: 5. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

* xx = gain group, e.g. BC817-16W-7.

Marking Information



XXX = Product Type Marking Code (See Page 1), e.g. K6A = BC817-16

YM = Date Code Marking

Y = Year ex: S = 2005

M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9